PCN Number: 202	10427000.2					I	PCN D	ate: Jun 1 2021					
Title: Qualification	of additiona	l HF	TF as ac	dditional Asseml	bly/1	Гest	site fo	or select devices					
Customer Contact:	PCN Manager		Dept:	Quality	Serv	ices	3						
Proposed 1 st Ship Da	ite: Nov 2	28 20	021	Estima	Date provided at								
Change Type:				ı	Ava	пар	ility:	sample request					
Assembly Site			Design				Wafer Bump Site						
Assembly Process			Data S					r Bump Material					
Assembly Material	S		Part nu	ımber change				r Bump Process					
Mechanical Specifi		\boxtimes	Test Si					r Fab Site					
Packing/Shipping/	Labeling		Test Pr	ocess		Н		r Fab Materials					
			DCN	Details		Ш	warei	r Fab Process					
Description of Chang	16'		PCN	Details									
Texas Instruments Inco Assembly/test site for differences and current	devices liste	d be	low in t	he product affe									
	UTL	2		HNA		T	FME	HFTF					
Mount Compound	SID#PZ			SID#400180			# A-03						
Mold Compound	SID#CZ		6	SID#450179	5		# R-07						
					Λ								
Lead Finish NiPdAu NiPdAu NiPdAu NiPdAu Matte Sn Bond wire diameter Au, 1.0 mils Au, 1.0 mils Au, 0.8 mils Au, 0.8 mils Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ. Upon expiry of this PCN TI will combine lead free solutions in a single standard part number, for the devices shown below. For example; 1P1G125QDCKRQ1 — can ship with both Matte Sn and NiPdAu. Example: - Customer order for 7500 units of 1P1G125QDCKRQ1 with 2500 units SPQ (Standard Pack Quantity per Reel). - TI can satisfy the above order in one of the following ways. I. 3 Reels of NiPdAu finish. II. 3 Reels of Matte Sn finish III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish. IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.													
Reason for Change:													
Supply continuity	P	_		0	12. 1	2124	- (-	data a fara di N					
Anticipated impact o	n Form, Fit	, Fu	nction	, Quality or Re	eliab	ility	y (pos	sitive / negative):					
None													

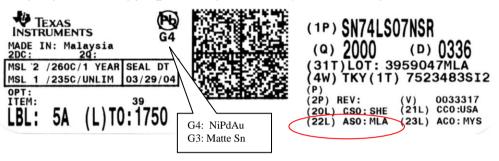
Ant	Anticipated impact on Material Declaration										
	No Impact to the	\boxtimes	Material Declarations or Product Content reports are driven								
	Material Declaration		from production data and will be available following the production release. Upon production release the revised								
			reports can be obtained at the site link below								

http://www.ti.com/quality/docs/materialcontentsearch.tsp

Changes to product identification resulting from this PCN:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City			
TFME	NFM	CHN	Economic Development Zone			
Hana Thailand	HNT	THA	Ayutthaya			
UTL2	NS2	THA	Bangpakong, Chachoengsao			
HFTF	HFT	CHN	Hefei			

Sample product shipping label (not actual product label)



Product Affected:

Group 1 (Current site = HNA, add HFTF as alternate) Device list:

1P1G125QDCKRQ1 SN74AUP1G08QDCKRQ1

Group 2 (Current site = TFME, add HFTF as alternate) Device list:

SN74AUP1T34QDCKRQ1 SN74LVC1G07QDCKRQ1 SN74LVC1G14QDCKRQ1

Group 3 (Current site = UTL2, add HFTF as alternate) Device list:

SN74LVC1G04QDCKRQ1	SN74LVC1G17QDCKRQ1	SN74LVC1G97QDCKRQ1	SN74LVC2G17QDCKRQ1
SN74LVC1G08QDCKRQ1	SN74LVC1G32QDCKRQ1	SN74LVC2G14IDCKRQ1	



Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approved 23-Jun-2020

Product Attributes

+							
Attributes	Qual Device: SN74LVC1G08QDCKRQ1	Qual Device: SN74LVC2G17QDCKRQ1	QBS Product Reference: SN74LVC1G04QDCKRQ1	QBS Product Reference: SN74LVC1G32QDCKRQ1	QBS Process Reference: SN74LVC04AQDRQ1	QBS Process Reference: SN74LVC1G08QDCKRQ1	QBS Package Reference: SN74LVC1G17DCKR
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range	-40 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +125 C
Product Function	Logic	Logic	Logic	Logic	Logic	Logic	Logic
Wafer Fab Supplier	FFAB	FFAB	FFAB	FFAB	FR-BIP-1	FFAB	FFAB
Die Revision	-	-	-	-	К	E	G
Assembly Site	HFTFAT	HFTFAT	HFTFAT	HFTFAT	MLA	NS2 (UTAC2)	HFTF
Package Type	SC70	SOT	SC70	SC70	SOIC; 3.91 x 8.65 MM	SOT	SC70
Package Designator	DCK DCK		DCK	DCK	D	DCK	DCK
Ball/Lead Count	5 6		5	5	14	5	5

QBS: Qual By Similarity
 Qual Device SN74LVC2G17QDCKRQ1 is qualified at LEVEL1-260C
 Qual Device SN74LVC1G17QDCKRQ1 is qualified at LEVEL1-260C
 Qual Device SN74LVC1G08QDCKRQ1 is qualified at LEVEL1-260C
 Qual Device SN74LVC1G125QDCKRQ1 is qualified at LEVEL1-260C

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Typ e	#	Test Spec	Mi n L ot Qt y	SS/ Lot	Test Name / Condition	Durati on	Qual Device: SN74LVC1G08Q DCKRQ1			Qual Device: SN74LVC1G32Q DCKRQ1	QBS Process Reference: SN74LVC04A QDRQ1	QBS Process Reference: SN74LVC1G08Q DCKRQ1	QBS Package Reference: SN74LVC1G1 7DCKR
Test G	roup A		lerate	d Envir	onment Stres	s Tests							
PC	A 1	JEDE C J- STD- 020 JESD 22- A113	3	77	Automotiv e Preconditi oning Level 1	(Level 1- 260C)	-	-	-	-	Pass	Pass	Pass
HA ST	A 2	JEDE C JESD 22- A110	3	77	Biased HAST, 130C/85% RH	96 Hours	-	-	-	-	-	-	3/231/0
HA ST	A 2	JEDE C JESD 22- A110	3	77	Biased HAST, 130C/85% RH	96 Hours	-	-	-	-	-	1/77/0	-
HA ST	A 2	JEDE C JESD 22- A110	3	77	Biased HAST, 130C/85% RH	96 Hours	-	-	-	-	-	-	3/240/0
AC	A 3	JEDE C JESD 22- A102	3	77	Autoclave 121C	96 Hours	-	-	-	-	-	-	3/231/0
AC	A 3	JEDE C JESD 22- A102	3	77	Autoclave 121C	96 Hours	-	-	-	-	1/77/0		-
тс	A 4	JEDE C JESD 22-	3	77	Temperatu re Cycle, - 65/150C	1000 Cycle s	-	-	1/77/0		1/77/0	-	

Typ e	#	Test Spec	Mi n L ot Qt y	SS/ Lot	Test Name / Condition	Durati on	Qual Device: SN74LVC1G08Q DCKRQ1	Qual Device: <u>SN74LVC2G17Q</u> <u>DCKRQ1</u>	Qual Device: SN74LVC1G04Q DCKRQ1	Qual Device: SN74LVC1G32Q DCKRQ1	QBS Process Reference: SN74LVC04A QDRQ1	QBS Process Reference: SN74LVC1G08Q DCKRQ1	QBS Package Reference: SN74LVC1G1 7DCKR
		A104 and Appe ndix 3											
PT C	A 5	JEDE C JESD 22- A105	1	45	Power Temperatu re Cycle	1000 Cycle s	N/A	N/A	-	-	-	-	-
HT SL	A 6	JEDE C JESD 22- A103	1	45	High Temp Storage Bake 170C	420 Hours	-	-	-	-	-	1/45/0	-
HT SL	A 6	JEDE C JESD 22- A103	1	45	High Temp Storage Bake, 170C	(420, 600 Hours)	-	-	-	-	-	-	3/231/0
Test G	roup		lerate	d Lifeti	me Simulatio	n Tests							
HT OL	B 1	JEDE C JESD 22- A108	3	77	Life Test, 125C	1000 Hours	-	-	-	-	-	1/77/0	-
HT OL	B 1	JEDE C JESD 22- A108	3	77	Life Test, 150C	300 Hours	-	-	-	-	-	-	3/231/0
HT OL	B 1	JEDE C JESD 22- A108	3	77	Life Test, 150C	500 Hours	-	2/154/0 -		-	-		
ELF R	B 2	AEC Q100- 008	3	800	Early Life Failure Rate, 125C	48 HOUR S	-			-	1/800/0	-	

Typ e	#	Test Spec	Mi n L ot Qt y	SS/ Lot	Test Name / Condition	Durati on	Qual Device: SN74LVC1G08Q DCKRQ1	Qual Device: <u>SN74LVC2G17Q</u> <u>DCKRQ1</u>	Qual Device: SN74LVC1G04Q DCKRQ1	Qual Device: SN74LVC1G32Q DCKRQ1	QBS Process Reference: SN74LVC04A QDRQ1	QBS Process Reference: SN74LVC1G08Q DCKRQ1	QBS Package Reference: SN74LVC1G1 7DCKR
ELF R	B 2	AEC Q100- 008	3	800	Early Life Failure Rate, 150C	24 Hours	-	-	-	-	2/1600/0	-	-
ED R	B 3	AEC Q100- 005	3	77	NVM Endurance , Data Retention, and Operationa I Life	-	N/A	N/A	-	-	-	-	-
Test (Grou		ckage	Assen	bly Integrity	Tests							
WB S	C 1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	Wires	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	3/90/0
WB P	C 2	MIL- STD8 83 Metho d 2011	1	30	Wire Bond Pull	Wires	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	3/90/0
SD	Сз	JEDE C JESD 22- B102	1	15	Solderabilit y	Pb Free Solder	-	-	-	-	-	-	3/66/0
PD	C 4	JEDE C JESD 22- B100 and B108	3	10	Physical Dimension s	Cpk>1 .67	1/30/0	1/30/0	1/30/0	1/30/0	-	-	-
Test	Gro	up D – Di	ie Fab	oricatio	n Reliability T	ests							
EM	D 1	JESD 61	-	-	Electromig ration	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	-	-	-	-	-
TD DB	D 2	JESD 35	-	-	Time Dependant	-	Completed Per Process	Completed Per Process	-	-	-	-	-

Typ e	#	Test Spec	Mi n L ot Qt y	SS/ Lot	Test Name / Condition	Durati on	Qual Device: SN74LVC1G08Q DCKRQ1	Qual Device: SN74LVC2G17Q DCKRQ1	Qual Device: SN74LVC1G04Q DCKRQ1	Qual Device: SN74LVC1G32Q DCKRQ1	QBS Process Reference: SN74LVC04A QDRQ1	QBS Process Reference: SN74LVC1G08Q DCKRQ1	QBS Package Reference: SN74LVC1G1 7DCKR
					Dielectric Breakdow n		Technology Requirements	Technology Requirements					
HCI	D 3	JESD 60 & 28	1	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Process Technology		ı	-	-
NB TI	D 4	-	1	-	Negative Bias Temperatu re Instability	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		-	-	-	-
SM	D 5	-	1	-	Stress Migration	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements		-	-	-	-
Te	st G	roup E –	Elect	rical Ve	rification Tes	ts							
HB M	E 2	AEC Q100- 002	1	3	ESD - HBM	2000V	-	1/3/0	-	-	-	-	-
HB M	E 2	AEC Q100- 002	1	3	ESD - HBM	4000V	1/3/0	-	1/3/0	1/3/0	-	-	-
CD M	E 3	AEC Q100- 011	1	3	ESD - CDM	1500V	1/3/0	1/3/0	1/3/0	1/3/0	ı	ı	-
LU	E 4	AEC Q100- 004	1	6	Latch-up	Elec Test (25C / 125C)	-	-	-	-	1	1/6/0	-
ED	E 5	AEC Q100- 009	3	30	Auto Electrical Distributio ns	Cpk>1 .67 Room, hot, and cold test	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	1/30/0	3/90/0

Test Group G – Cavity Package Integrity Tests													
DS	G7	MIL-STD-883 Method 2019	1	5	Die Shear	QSS 009-009	-	-	-	-	-	-	3/30/0

A1 (PC): Preconditioning:
Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level: Grade 0 (or E): $-40^{\circ}\mathrm{C}$ to $+150^{\circ}\mathrm{C}$ Grade 1 (or Q): $-40^{\circ}\mathrm{C}$ to $+125^{\circ}\mathrm{C}$ Grade 2 (or T): $-40^{\circ}\mathrm{C}$ to $+105^{\circ}\mathrm{C}$ Grade 3 (or I): $-40^{\circ}\mathrm{C}$ to $+85^{\circ}\mathrm{C}$

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
WW PCN Team	PCN www admin_team@list.ti.com

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.